

Schottky Barrier Rectifier

MBR2030CTL

FEATURES

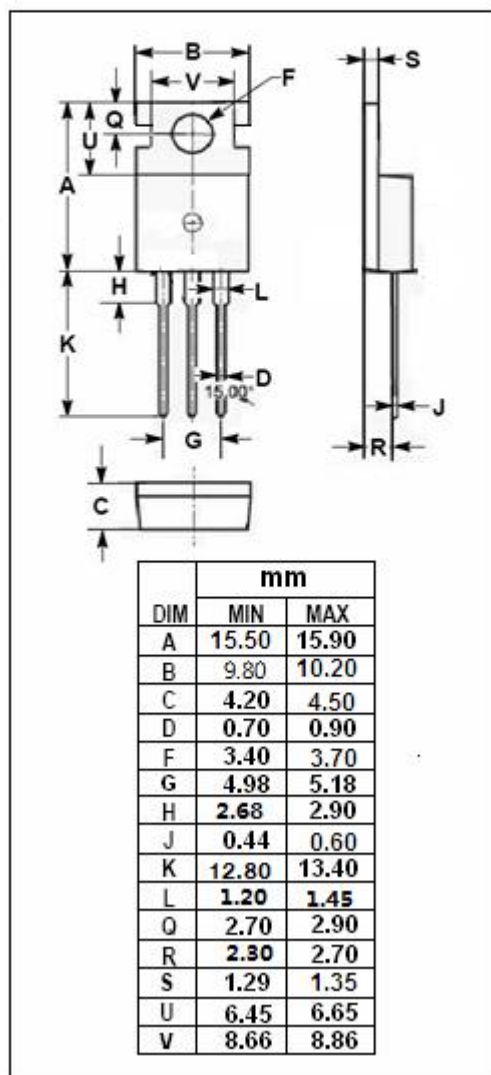
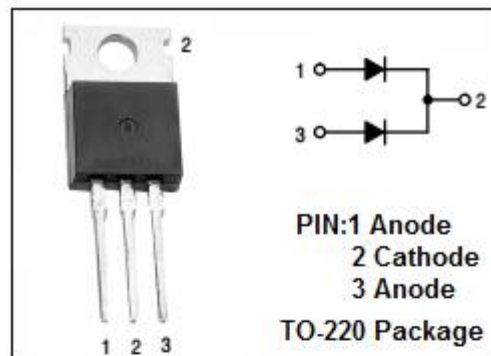
- Guard -Ring for Stress Protection
- Low Forward Voltage
- High Operating Junction Temperature
- High dv/dt capability
- Pb-Free Packages are Available
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

MECHANICAL CHARACTERISTICS

- Case: Epoxy, Molded
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{RRM} V _{RWM} V _R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	30	V
I _{F(AV)}	Average Rectified Forward Current (Rated V _R)	10	A
I _{FSM}	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	150	A
I _{RRM}	Peak Repetitive Reverse Surge Current (20 μs, 1.0kHz)	1.0	A
T _J	Junction Temperature	-65~150	°C
T _{stg}	Storage Temperature Range	-65~175	°C
dv/dt	Voltage Rate of Change (Rated V _R)	1000	V/μs



Schottky Barrier Rectifier**MBR2030CTL****THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	2.0	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=5.0ms, Duty Cycle $\leq$ 10%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V_F	Maximum Instantaneous Forward Voltage	$I_F = 10A ; T_C = 25^{\circ}C$ $I_F = 10A ; T_C = 150^{\circ}C$ $I_F = 20A ; T_C = 25^{\circ}C$ $I_F = 20A ; T_C = 150^{\circ}C$	0.52 0.40 0.58 0.48	V
I_R	Maximum Instantaneous Reverse Current	Rated DC Voltage, $T_C = 25^{\circ}C$ Rated DC Voltage, $T_C = 125^{\circ}C$	0.1 7.5	mA